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FORM PTO 1449 (*modified*)

U.S. DEPARTMENT OF COMMERCE
PATENT AND TRADEMARK OFFICE

LIST OF REFERENCES CITED BY APPLICANT(S)
(Use several sheets if necessary)

November 3, 2003

ATTY DOCKET NO. 00862.022311.1	APPLICATION NO. 10/678,146
APPLICANT Kazutaka YANAGITA et al.	
FILING DATE October 6, 2003	GROUP Unassigned

U.S. PATENT DOCUMENTS

*EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
KP		US-6,376,332	05/23/2002	Yanagita et al.	438	458	

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION YES/NO/ OR ABSTRACT

OTHER DOCUMENT(S) (Including Author, Title, Date, Pertinent Pages, Etc.)

EXAMINER	DATE CONSIDERED
	11/19/04

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

FORM PTO 1449 (*modified*)

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LIST OF REFERENCES CITED BY APPLICANT(S)
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October 6, 2003

ATTY DOCKET NO. 00862.022311.1	APPLICATION NO. Divisional of Appln. No. 09/910,017, filed July 23, 2001
APPLICANT Kazutaka YANAGITA et al.	
FILING DATE October 6, 2003	GROUP 2822

U.S. PATENT DOCUMENTS

*EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
PEP		US-5-371,037	12/06/1994	Yonehara	437	86	
PEP		US-5,856,229	01/05/1999	Sakaguchi et al.	438	406	
PEP		US-5,869,386	02/09/1999	Hamajima et al.	438	455	
PEP		US-6,214,701	04/10/2001	Matsushita et al.	438	458	
PEP		US-5,811,348	09/22/1998	Matsushita et al.	438	455	
PEP		2002/0096717	07/25/2002	Chu et al.	257	347	

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION YES/NO/ OR ABSTRACT
PEP		5-21338	01/29/1993	Japan			Abstract
PEP		7-302889	11/14/1995	Japan			Abstract

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		Nagano, K, *et al.* "Oxidized Porous Silicon and It's Application," Semiconductor Research Lab, Matsushita Electric Industrial Co., Ltd.
PEP		Uhlir, A., Jr. "Electrolytic Shaping of Germanium and Silicon," The Bell System Technical Journal, V. 35, 1956. Pp. 333-347.
PEP		Unagami, T. "Formation Mechanisms of Porous Silicon Layer by Anodization in HF Solution," Journal of the Electrochemical Society, V. 127, No. 2, February 1980. Pp. 476-483.
		Holmstrom, R.P., *et al.* "Complete dielectric isolation by highly selective and self-stopping formation of oxidized porous silicon," Applied Physics Letter, V. 42, No. 4, February 15, 1983. Pp. 38-388.
PEP		Imai, K. "A New Dielectric Isolation Method Using Porous Silicon," Solid State Electronics, An International Journal, V. 24, No. 2, February 1981. Pp. 159-164.

EXAMINER	DATE CONSIDERED
[signature]	11/19/04

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